

## Differential Hall Effect Sensor IC

in CMOS technology

## Introduction

The HAL320 is a differential Hall switch produced in CMOS technology. The sensor includes 2 temperaturecompensated Hall plates ( 2.25 mm apart) with active offset compensation, a differential amplifier with a Schmitt trigger, and an open-drain output transistor (see Fig. 2).

The HAL320 is a differential sensor which responds to spatial differences of the magnetic field. The Hall voltages at the two Hall plates, $\mathrm{S}_{1}$ and $\mathrm{S}_{2}$, are amplified with a differential amplifier. The differential signal is compared with the actual switching level of the internal Schmitt trigger. Accordingly, the output transistor is switched on or off. The sensor has a bipolar switching behavior and requires positive and negative values of $\Delta \mathrm{B}=\mathrm{B}_{\mathrm{S} 1}-\mathrm{B}_{\mathrm{S} 2}$ for correct operation.

Basically, there are two ways to generate the differential signal $\Delta \mathrm{B}$ :

- Rotating a multi-pole-ring in front of the branded side of the package (see Fig. 4, Fig. 5, and Fig. 6).
- Back-bias applications:

A magnet on the back side of the package generates a back-bias field at both Hall plates. The differential signal $\Delta \mathrm{B}$ results from the magnetic modulation of the back-bias field by a rotating ferromagnetic target.

The active offset compensation leads to constant magnetic characteristics over supply voltage and temperature.

The sensor is designed for industrial and automotive applications and operates with supply voltages from 4.5 V to 24 V in the ambient temperature range from $-40^{\circ} \mathrm{C}$ up to $150{ }^{\circ} \mathrm{C}$.

The HAL320 is an ideal sensor for target wheel applications, ignition timing, anti-lock brake systems, and revolution counting in extreme automotive and industrial environments

The HAL320 is available in two SMD-packages (SOT-89A and SOT-89B) and in a leaded version (TO-92UA).

## Features:

- distance between Hall plates: 2.25 mm
- operates from 4.5 V to 24 V supply voltage
- switching offset compensation at 62 kHz
- overvoltage protection
- reverse-voltage protection of $V_{D D}$-pin
- short-circuit protected open-drain output by thermal shutdown
- operates with magnetic fields from DC to 10 kHz
- output turns low with magnetic south pole on branded side of package and with a higher magnetic flux density in sensitive area S1 as in S2
- on-chip temperature compensation circuitry minimizes shifts of the magnetic parameters over temperature and supply voltage range
- EMC corresponding to DIN 40839


## Marking Code

| Type | Temperature Range |  |  |
| :--- | :---: | :---: | :---: |
|  | A | E | C |
| HAL320SF, <br> HAL320SO, <br> HAL320UA | 320 A | 320 E | 320 C |

## Operating Junction Temperature Range ( $\mathrm{T}_{\mathbf{J}}$ )

A: $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $+170^{\circ} \mathrm{C}$
$\mathrm{E}: \mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $+100^{\circ} \mathrm{C}$
C: $\mathrm{T}_{\mathrm{J}}=0^{\circ} \mathrm{C}$ to $+100^{\circ} \mathrm{C}$
The relationship between ambient temperature $\left(T_{A}\right)$ and junction temperature $\left(T_{J}\right)$ is explained on page 11.

## Hall Sensor Package Codes

HALXXXPA-T


Type: 320

Example: HAL320UA-E
$\rightarrow$ Type: 320
$\rightarrow$ Package: TO-92UA
$\rightarrow$ Temperature Range: $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $+100^{\circ} \mathrm{C}$
Hall sensors are available in a wide variety of packaging versions and quantities. For more detailed information, please refer to the brochure: "Ordering Codes for Hall Sensors".

## Solderability

- Package SOT-89A and SOT-89B: according to IEC68-2-58
- Package TO-92UA: according to IEC68-2-20


Fig. 1: Pin configuration

## Functional Description

This Hall effect sensor is a monolithic integrated circuit with 2 Hall plates 2.25 mm apart that switches in response to differential magnetic fields. If magnetic fields with flux lines at right angles to the sensitive areas are applied to the sensor, the biased Hall plates force Hall voltages proportional to these fields. The difference of the Hall voltages is compared with the actual threshold level in the comparator. The temperature-dependent bias increases the supply voltage of the Hall plates and adjusts the switching points to the decreasing induction of magnets at higher temperatures. If the differential magnetic field exceeds the threshold levels, the open drain output switches to the appropriate state. The builtin hysteresis eliminates oscillation and provides switching behavior of the output without oscillation.

Magnetic offset caused by mechanical stress at the Hall plates is compensated for by using the "switching offset compensation technique": An internal oscillator provides a two phase clock (see Fig. 3). The difference of the Hall voltages is sampled at the end of the first phase. At the end of the second phase, both sampled differential Hall voltages are averaged and compared with the actual switching point. Subsequently, the open drain output switches to the appropriate state. The amount of time that elapses from crossing the magnetic switch level to the actual switching of the output can vary between zero and $1 /$ fosc $_{\text {os }}$.

Shunt protection devices clamp voltage peaks at the Output-Pin and $\mathrm{V}_{\mathrm{DD}}$-Pin together with external series resistors. Reverse current is limited at the $V_{D D}$-Pin by an internal series resistor up to -15 V . No external reverse protection diode is needed at the $\mathrm{V}_{\mathrm{DD}}$-Pin for values ranging from 0 V to -15 V .


Fig. 2: HAL320 block diagram


Fig. 3: Timing diagram

## Outline Dimensions



Fig. 4:
Plastic Small Outline Transistor Package (SOT-89A)
Weight approximately 0.04 g Dimensions in mm


## Fig. 5:

Plastic Transistor Single Outline Package (TO-92UA)
Weight approximately 0.12 g
Dimensions in mm


Fig. 6:
Plastic Small Outline Transistor Package (SOT-89B)
Weight approximately 0.04 g
Dimensions in mm

## Dimensions of Sensitive Areas

$0.08 \mathrm{~mm} \times 0.17 \mathrm{~mm}$ (each)

## Positions of Sensitive Areas

| SOT-89A | SOT-89B | TO-92UA |
| :--- | :---: | :--- |
| $x_{1}=-1.125 \mathrm{~mm} \pm 0.2 \mathrm{~mm}$ |  |  |
| $x_{2}=1.125 \mathrm{~mm} \pm 0.2 \mathrm{~mm}$ |  |  |
| $x_{2}-x_{1}=2.25 \mathrm{~mm} \pm 0.01 \mathrm{~mm}$ |  |  |
| $\mathrm{y}=0.98 \mathrm{~mm}$ <br> $\pm 0.2 \mathrm{~mm}$ | $\mathrm{y}=0.95 \mathrm{~mm}$ | $\mathrm{y}=1.0 \mathrm{~mm}$ |
|  | $\pm 0.2 \mathrm{~mm}$ | $\pm 0.2 \mathrm{~mm}$ |

$\mathrm{x}_{1}$ and $\mathrm{x}_{2}$ are referenced to the center of the package

## Absolute Maximum Ratings

| Symbol | Parameter | Pin No. | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{D D}$ | Supply Voltage | 1 | -15 | 281) | V |
| $-V_{P}$ | Test Voltage for Supply | 1 | $-24^{2}$ | - | V |
| $-_{\text {ID }}$ | Reverse Supply Current | 1 | - | 501) | mA |
| $\mathrm{I}_{\text {DDZ }}$ | Supply Current through Protection Device | 1 | -2003) | 2003) | mA |
| $\mathrm{V}_{\mathrm{O}}$ | Output Voltage | 3 | -0.3 | 281) | V |
| $\mathrm{l}_{0}$ | Continuous Output On Current | 3 | - | 30 | mA |
| $\mathrm{I}_{\text {max }}$ | Peak Output On Current | 3 | - | 2503) | mA |
| l OZ | Output Current through Protection Device | 3 | -2003) | 2003) | mA |
| $\mathrm{T}_{S}$ | Storage Temperature Range |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{J}}$ | Junction Temperature Range |  | $\begin{aligned} & -40 \\ & -40 \end{aligned}$ | $\begin{aligned} & 150 \\ & 170^{4} \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |
| ${ }^{1)}$ as long as $T_{J} m a x$ is not exceeded <br> 2) with a $220 \Omega$ series resistance at pin 1 corresponding to test circuit 1 <br> 3) $t<2 \mathrm{~ms}$ <br> 4) $t<1000 \mathrm{~h}$ |  |  |  |  |  |

Stresses beyond those listed in the "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions/Characteristics" of this specification is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

## Recommended Operating Conditions

| Symbol | Parameter | Pin No. | Min. | Max. | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{DD}}$ | Supply Voltage | 1 | 4.5 | 24 | V |
| $\mathrm{I}_{\mathrm{O}}$ | Continuous Output On Current | 3 | - | 20 | mA |
| $\mathrm{~V}_{\mathrm{O}}$ | Output Voltage | 3 | - | 24 | V |
| $\mathrm{R}_{\mathrm{V}}$ | Series Resistor | 1 | - | 270 | $\Omega$ |

Electrical Characteristics at $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $+170^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}$ to 24 V , as not otherwise specified in Conditions Typical Characteristics for $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}$

| Symbol | Parameter | Pin No. | Min. | Typ. | Max. | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $l_{\text {D }}$ | Supply Current | 1 | 2.8 | 4.7 | 6.8 | mA | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |
| IDD | Supply Current over Temperature Range | 1 | 1.8 | 4.7 | 7.5 | mA |  |
| $V_{\text {DDZ }}$ | Overvoltage Protection at Supply | 1 | - | 28.5 | 32.5 | v | $\begin{aligned} & \mathrm{I}_{\mathrm{DD}}=25 \mathrm{~mA}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \\ & \mathrm{t}=20 \mathrm{~ms} \end{aligned}$ |
| $\mathrm{V}_{\text {OZ }}$ | Overvoltage Protection at Output | 3 | - | 28 | 32.5 | v | $\begin{aligned} & \mathrm{I}_{\mathrm{OH}}=25 \mathrm{~mA}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \\ & \mathrm{t}=20 \mathrm{~ms} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage | 3 | - | 170 | 250 | mV | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=20 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage over Temperature Range | 3 | - | 170 | 400 | mV | $\mathrm{l}_{0}=20 \mathrm{~mA}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Voltage over Temperature Range | 3 | - | 210 | 500 | mV | $\mathrm{l}_{0}=25 \mathrm{~mA}$ |
| IOH | Output Leakage Current | 3 | - | - | 1 | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}=4.5 \mathrm{~V} \ldots 24 \mathrm{~V}, \\ & \Delta \mathrm{~B}<\Delta \mathrm{B}_{\mathrm{OFF}}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |
| IOH | Output Leakage Current over Temperature Range | 3 | - | - | 10 | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}=4.5 \mathrm{~V} \ldots 24 \mathrm{~V}, \\ & \Delta \mathrm{~B}<\Delta \mathrm{B}_{\mathrm{OFF}}, \mathrm{~T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C} \end{aligned}$ |
| $\mathrm{f}_{\text {osc }}$ | Internal Oscillator Chopper Frequency | - | 42 | 62 | 75 | kHz | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |
| $\mathrm{f}_{\text {osc }}$ | Internal Oscillator Chopper Frequency over Temperature Range | - | 40 | 62 | 80 | kHz |  |
| $\mathrm{t}_{\text {en( }}(\mathrm{O})$ | Enable Time of Output after Setting of $V_{D D}$ | 3 | - | 35 | - | $\mu \mathrm{s}$ | $\begin{aligned} & V_{D D}=12 \mathrm{~V}, \\ & \Delta \mathrm{~B}>\Delta \mathrm{B}_{\text {ON }}+2 \mathrm{mT} \text { or } \\ & \Delta \mathrm{B}<\Delta \mathrm{B}_{\text {OFF }}-2 \mathrm{mT} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time | 3 | - | 80 | 400 | ns | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}, \mathrm{RL}=820 \Omega, \\ & \mathrm{CL}=20 \mathrm{pF} \end{aligned}$ |
| $t_{f}$ | Output Fall Time | 3 | - | 50 | 400 | ns | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}, \mathrm{RL}=820 \Omega, \\ & \mathrm{CL}=20 \mathrm{pF} \end{aligned}$ |
| $\begin{aligned} & \mathrm{R}_{\text {thJJB }} \\ & \text { case } \\ & \text { SOT-89A, } \\ & \text { SOT-89B } \end{aligned}$ | Thermal Resistance Junction to Substrate Backside |  | - | 150 | 200 | K/W | Fiberglass Substrate $30 \mathrm{~mm} \times 10 \mathrm{~mm} \times 1.5 \mathrm{~mm}$, pad size see Fig. 8 |
| $\mathrm{R}_{\mathrm{th} \mathrm{JS}}$ case TO-92UA | Thermal Resistance Junction to Soldering Point |  | - | 150 | 200 | K/W |  |

Magnetic Characteristics at $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $+170^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}$ to 24 V
Typical Characteristics for $\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V}$
Magnetic flux density values of switching points (Condition: - $10 \mathrm{mT}<\mathrm{B}_{0}<10 \mathrm{mT}$ )
Positive flux density values refer to the magnetic south pole at the branded side ot the package. $\Delta B=B_{S 1}-B_{S 2}$

| Parameter | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $100{ }^{\circ} \mathrm{C}$ |  |  | $170{ }^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| $\begin{aligned} & \text { On point } \Delta \mathrm{B}_{\mathrm{ON}} \\ & \Delta \mathrm{~B}>\Delta \mathrm{B}_{\mathrm{ON}} \end{aligned}$ | -1.5 | 1.2 | 2.5 | -1.5 | 1.2 | 2.5 | -2 | 1.2 | 3 | -2.5 | 1.1 | 3.5 | mT |
| $\text { Off point } \Delta \mathrm{B}_{\text {OFF }}$ $\Delta \mathrm{B}<\Delta \mathrm{B}_{\text {OFF }}$ | -2.5 | -0.6 | 1.5 | -2.5 | -0.6 | 1.5 | -3 | -0.5 | 2 | -3.5 | -0.4 | 2.5 | mT |
| Hysteresis <br> $\Delta \mathrm{B}_{\mathrm{HYS}}=\Delta \mathrm{B}_{\mathrm{ON}}-\Delta \mathrm{B}_{\mathrm{OFF}}$ | 1 | 1.8 | 4 | 1 | 1.8 | 4 | 1 | 1.7 | 4 | 0.8 | 1.5 | 4 | mT |
| $\begin{aligned} & \text { Offset } \Delta \mathrm{B}_{\text {OFFSET }}= \\ & \left(\Delta \mathrm{B}_{\mathrm{ON}}+\Delta \mathrm{B}_{\mathrm{OFF}} / 2 / 2\right. \end{aligned}$ | -2 | 0.3 | 2 | -2 | 0.3 | 2 | -2.5 | 0.4 | 2.5 | -3 | 0.4 | 3 | mT |

In back-biased applications, sensitivity mismatch between the two Hall plates $S_{1}$ and $S_{2}$ can lead to an additional offset of the magnetic switching points. In back-biased applications with the magnetic preinduction $B_{0}$, this sensitivity mismatch generates the magnetic offset $\Delta \mathrm{B}_{\text {OFFSETbb }}=\left|\mathrm{S}_{1}-\mathrm{S}_{2}\right| / \mathrm{S}_{1} \cdot \mathrm{~B}_{0}+\Delta \mathrm{B}_{\text {OFFSET }}$.

| Parameter | $\mathbf{- 4 0}{ }^{\circ} \mathbf{C}$ | $\mathbf{2 5}{ }^{\circ} \mathbf{C}$ | $100^{\circ} \mathbf{C}$ | $\mathbf{1 7 0}{ }^{\circ} \mathbf{C}$ | Unit |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| Sensitivity mismatch ${ }^{1)}$ | $\left\|\mathrm{S}_{1}-\mathrm{S}_{2}\right\| / \mathrm{S}_{1}$ | $1.5^{2)}$ | $1.0^{2)}$ | $1.0^{2)}$ | $0.5^{2)}$ | $\%$ |

1) Mechanical stress from packaging can influence sensitivity mismatch.
2) All values are typical values.

The magnetic switching points are checked at room temperature at a magnetic preinduction of $B_{0}=150 \mathrm{mT}$. These magnetic parameters may change under external pressure and during the lifetime of the sensor.

| Parameter | $\mathbf{2 5}{ }^{\circ} \mathbf{C}$ |  |  | Unit |
| :--- | :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. |  |
| On point $\Delta \mathrm{B}_{\mathrm{ONbb}}$ | -4.5 | 1.5 | 5.5 | mT |
| Off point $\Delta \mathrm{B}_{\text {OFFbb }}$ | -5.5 | -0.3 | 4.5 | mT |
| Hysteresis $\Delta \mathrm{B}_{\text {HYS }}$ | 1 | 1.8 | 4 | mT |
| Offset $\Delta \mathrm{B}_{\text {OFFSETbb }}$ | -5 | 0.6 | +5 | mT |



Fig. 7: Definition of switching points and hysteresis


Fig. 8: Recommended pad size for SOT-89A and SOT-89B; Dimensions in mm


Fig. 9: Magnetic switch points versus temperature


Fig. 10: Magnetic switch points
versus supply voltage


Fig. 11: Magnetic switch points versus supply voltage


Fig. 12: Supply current versus supply voltage


Fig. 13: Supply current versus supply voltage


Fig. 14: Supply current versus ambient temperature


Fig. 15: Internal chopper frequency versus ambient temperature


Fig. 16: Output low voltage versus supply voltage


Fig. 17: Output low voltage versus supply voltage


Fig. 18: Output low voltage versus ambient temperature


Fig. 19: Output high current versus output voltage


Fig. 20: Output leakage current versus ambient temperature

## Application Notes

Mechanical stress can change the sensitivity of the Hall plates and an offset of the magnetic switching points may result. External mechanical stress on the sensor must be avoided if the sensor is used under back-biased conditions. This piezo sensitivity of the sensor IC cannot be completely compensated for by the switching offset compensation technique.

In order to assure switching the sensor on and off in a back-biased application, the minimum magnetic modulation of the differential field should amount to more than $10 \%$ of the magnetic preinduction.

If the HAL320 sensor IC is used in back-biased applications, please contact our Application Department. They will provide assistance in avoiding applications which may induce stress to the ICs. This stress may cause drifts of the magnetic parameters indicated in this data sheet.

For electromagnetic immunity, it is recommended to apply a 4.7 nF capacitor between $\mathrm{V}_{\mathrm{DD}}$ (pin 1) and Ground (pin 2). For automotive applications, a $220 \Omega$ series resistor to pin 1 is recommended. Because of the $I_{D D}$ peak at 3.5 V , the series resistor should not be greater than $270 \Omega$. The series resistor and the capacitor should be placed as close as possible to the IC. For optimal EMC behavior, the test circuits in Fig. 21 and Fig. 22 are recommended.

## Ambient Temperature

Due to the internal power dissipation, the temperature on the silicon chip (junction temperature $\mathrm{T}_{\mathrm{J}}$ ) is higher than the temperature outside the package (ambient temperature $\mathrm{T}_{\mathrm{A}}$ ).
$\mathrm{T}_{\mathrm{J}}=\mathrm{T}_{\mathrm{A}}+\Delta \mathrm{T}$
At static conditions, the following equations are valid:

- for SOT-89x: $\quad \Delta T=I_{D D} * V_{D D}{ }^{*} R_{\text {thJSB }}$
- for TO-92UA: $\quad \Delta T=I_{D D} * V_{D D}{ }^{*} R_{\text {thJA }}$

For typical values, use the typical parameters. For worst case calculation, use the max. parameters for $I_{D D}$ and $\mathrm{R}_{\text {th }}$, and the max. value for $\mathrm{V}_{\mathrm{DD}}$ from the application.

## Recommended Test Circuits

 for Electromagnetic CompatibilityTest pulses $\mathrm{V}_{\text {EMC }}$ corresponding to DIN 40839.


Fig. 21: Test circuit 2: test procedure for class $A$


Fig. 22: Test circuit 1: test procedure for class $C$

## Data Sheet History

1. Final data sheet: "HAL320 Differential Hall Effect Sensor IC", July 15, 1998, 6251-439-1DS. First release of the final data sheet.

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| Subject: | Improvement of SOT-89B Package |
| :--- | :--- |
| Data Sheet Concerned: | HAL 300, 6251-345-1DS, Edition July 15, 1998 |
|  | HAL 320, 6251-439-1DS, Edition July 15, 1998 |
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## Changes:

- position tolerance of the sensitive area reduced
- tolerances of the outline dimensions reduced
- thickness of the leadframe changed to 0.15 mm (old 0.125 mm )
- HAL 300 now available in SOT-89B
- SOT-89A will be discontinued in December 2000


Position of sensitive area

|  | HAL 300 | HAL 320 |
| :--- | :--- | :--- |
| $x_{1}+x_{2}$ | $(2.05 \pm 0.001) \mathrm{mm}$ | $(2.25 \pm 0.001) \mathrm{mm}$ |
| $x_{1}=x_{2}$ | 1.025 mm nominal | 1.125 mm nominal |
| $y$ | 0.95 mm nominal | 0.95 mm nominal |

Note: A mechanical tolerance of $\pm 0.05 \mathrm{~mm}$ applies to all dimensions where no tolerance is explicitly given. Position tolerances of the sensitive areas are defined in the package diagram.

